AM3455P

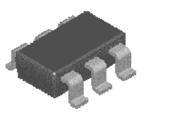
Analog Power

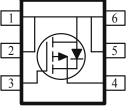
P-Channel 30V (D-S) MOSFET

These miniature surface mount MOSFETs utilize High Cell Density process. Low $r_{DS(on)}$ assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are power switch, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r_{DS(on)} Provides Higher Efficiency and Extends Battery Life
- Low Gate Charge
- Fast Switch
- Miniature TSOP-6 Surface Mount Package Saves Board Space

| PRODUCT SUMMARY | | | |
|---------------------|--------------------------------|-----|--|
| V _{DS} (V) | $r_{DS(on)}(\Omega)$ $I_D(A)$ | | |
| -30 | 0.112 @ V _{GS} = 10 V | 3.4 | |
| | $0.172 @ V_{GS} = 4.5V$ | 2.7 | |





| ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED) | | | | | | |
|--|--|-----------------|------------|-------|--|--|
| Parameter | | | Maximum | Units | | |
| Drain-Source Voltage | | | -30 V | | | |
| Gate-Source Voltage | | | ±20 | v | | |
| Continuous Drain Current ^a | $T_A=25^{\circ}C$ | T _n | 3.4 | А | | |
| Continuous Drain Current | $T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$ | тр | 2.6 | | | |
| Pulsed Drain Current ^b | | I _{DM} | ±20 | ±20 | | |
| Continuous Source Current (Diode Conduction) ^a | | | 1.7 | А | | |
| | $T_A=25^{\circ}C$ | D | 2.0 | W | | |
| Power Dissipation ^a | $T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$ | ГD | 1.3 | ٧V | | |
| Operating Junction and Storage Temperature Range | | | -55 to 150 | °C | | |

| THERMAL RESISTANCE RATINGS | | | | | |
|--|--------------|-------------------|---------|-------|--|
| Parameter | | Symbol | Maximum | Units | |
| Maximum Junction-to-Ambient ^a | t <= 5 sec | D | 62.5 | °C/W | |
| | Steady-State | R _{THJA} | 110 | | |

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

| SPECIFICATIONS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED) | | | | | | | |
|--|---------------------|--|--------|-----|------|------|--|
| Parameter | Symbol | Test Conditions | Limits | | | Unit | |
| i ar anne te i | Symbol | Test conditions | Min | Тур | Max | Omt | |
| Static | | | | | | - | |
| Gate-Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_D = 250 \text{ uA}$ | 1.0 | | | v | |
| Gate-Body Leakage | Igss | $V_{DS} = 0 V, V_{GS} = \pm 20 V$ | | | ±100 | nA | |
| Zero Gate Voltage Drain Current | IDSS | $V_{DS} = -24 V$, $V_{GS} = 0 V$ | | | 1 | | |
| Zelo Gate voltage Dialii Current | IDSS | $V_{DS} = -24 V, V_{GS} = 0 V, T_J = 55^{\circ}C$ | | | 50 | uA | |
| On-State Drain Current ^A | ID(on) | $V_{DS} = 5 V, V_{GS} = 10 V$ | 10 | | | Α | |
| Drain-Source On-Resistance ^A | rDS(on) | $V_{GS} = 10 V$, $I_D = 3.4 A$ | | | 112 | mΩ | |
| | | $V_{GS} = 4.5 \text{ V}, I_D = 2.7 \text{ A}$ | | | 172 | | |
| Forward Tranconductance ^A | g _{fs} | $V_{DS} = 4.5 V$, $I_D = 3.4 A$ | | 6 | | S | |
| Diode Forward Voltage | Vsd | $I_S = 0.75 A$, $V_{GS} = 0 V$ | | | 1.2 | V | |
| Dynamic ^b | | | | | | | |
| Total Gate Charge | Qg | $V_{DS} = 30 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 3.4 \text{ A}$ | | 4.5 | | nC | |
| Gate-Source Charge | Qgs | | | 1.4 | | | |
| Gate-Drain Charge | Qgd | | | 2.4 | | | |
| Turn-On Delay Time | td(on) | | | 9 | | | |
| Rise Time | tr | $V_{DD} = 30 \text{ V}, R_L = 30 \Omega, I_D = 1 \text{ A}, \\ V_{GEN} = 10 \text{ V}$ | | 12 | | ns | |
| Turn-Off Delay Time | td(off) | | | 25 | | | |
| Fall-Time | tf | | | 14 | | | |

Notes

a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.

b. Guaranteed by design, not subject to production testing.

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